

BAS101; BAS101S High-voltage switching diodes Rev. 02 — 14 December 2009

Product data sheet

Product profile

1.1 General description

High-voltage switching diodes, encapsulated in a SOT23 small Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
BAS101	SOT23	-	single
BAS101S	SOT23	-	dual series

1.2 Features

- High switching speed: $t_{rr} \le 50$ ns
- Low leakage current
- Repetitive peak reverse voltage: $V_{RRM} \le 300 \text{ V}$
- Low capacitance: C_d ≤ 2 pF
- Reverse voltage: V_R ≤ 300 V
- Small SMD plastic package

1.3 Applications

- High-speed switching
- High-voltage switching

- Voltage clamping
- Reverse polarity protection

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		-	-	200	mA
I _R	reverse current	$V_{R} = 250 \text{ V}$	-	-	150	nA
V_R	reverse voltage		-	-	300	V
t _{rr}	reverse recovery time		<u>[1]</u> -	-	50	ns

^[1] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.



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Pinning information 2.

Pinning		
Description	Simplified outline	Symbol
anode		
not connected	3	3
cathode	1 2	1 - 2 006aaa764
anode (diode 1)		
cathode (diode 2)	3	3
cathode (diode 1), anode (diode 2)	1 2	1 2 2 006aaa763
	Description anode not connected cathode anode (diode 1) cathode (diode 2) cathode (diode 1),	anode not connected cathode anode (diode 1) cathode (diode 2) cathode (diode 2) cathode (diode 2) anode (diode 2)

Ordering information 3.

Ordering information Table 4.

Type number	Package				
	Name	Description	Version		
BAS101	-	plastic surface-mounted package; 3 leads	SOT23		
BAS101S					

Marking 4.

Product data sheet

Table 5. **Marking codes**

Type number	Marking code ^[1]
BAS101	*HQ
BAS101S	*HR

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse		-	300	V
	voltage	series connection	-	600	V
V _R reverse voltage	reverse voltage		-	300	V
		series connection	-	600	V
I _F	forward current		-	200	mA
		series connection	-	100	mA
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	1	Α
I _{FSM}	non-repetitive peak forward current	square wave; $t_p \le 1 \mu s$	<u>[1]</u> _	9	Α
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2] _	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] $T_j = 25$ °C prior to surge

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] -	-	500	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

7. Characteristics

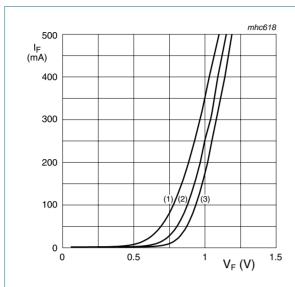
Table 8. Characteristics

 $T_{amb} = 25 \, ^{\circ}\text{C}$ unless otherwise specified.

· amb = 0	o armoso surer mos spos					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diod	е					
V_{F}	forward voltage	I _F = 100 mA	<u>[1]</u> _	-	1.1	V
I _R	reverse current	V _R = 250 V	-	-	150	nA
		$V_R = 250 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
C_d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$	-	-	2	pF
t _{rr}	reverse recovery time		[2] _	-	50	ns

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

^[2] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.



- (1) T_{amb} = 150 °C
- (2) $T_{amb} = 75 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values

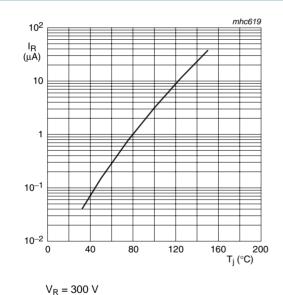
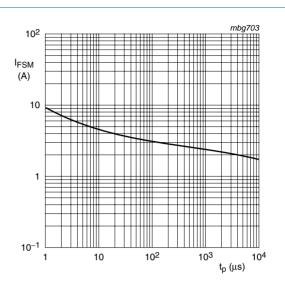


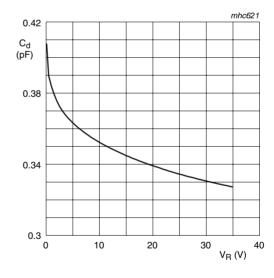
Fig 3. Reverse current as a function of junction temperature; typical values



Based on square wave currents

T_i = 25 °C; prior to surge

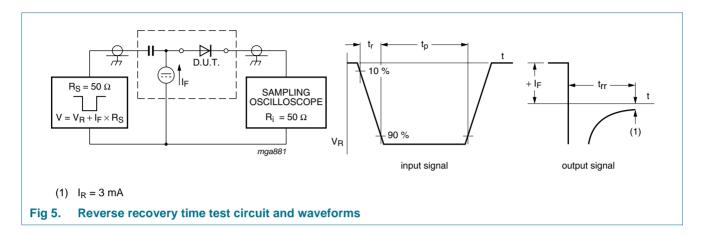
Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



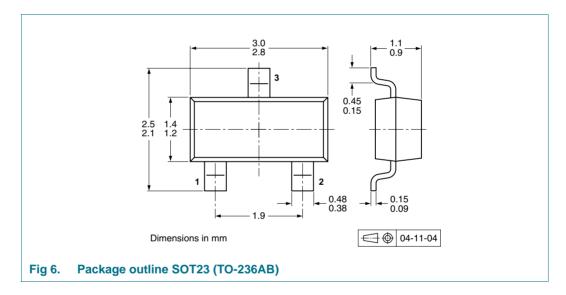
 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values

8. Test information



9. Package outline



10. Packing information

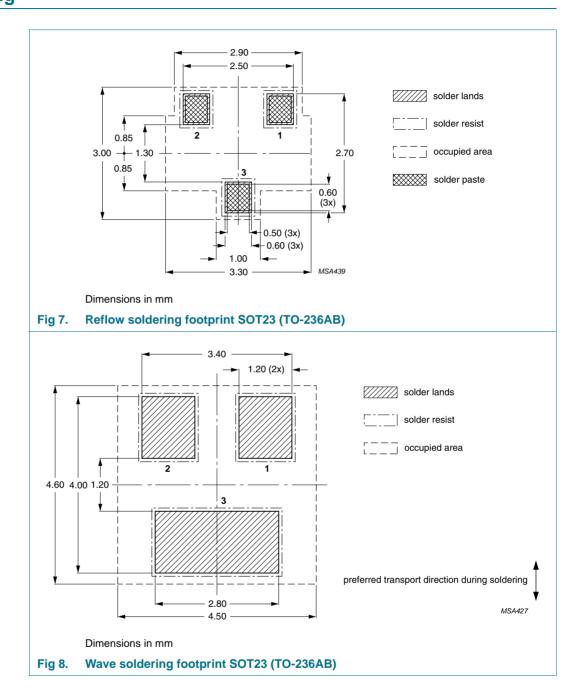
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

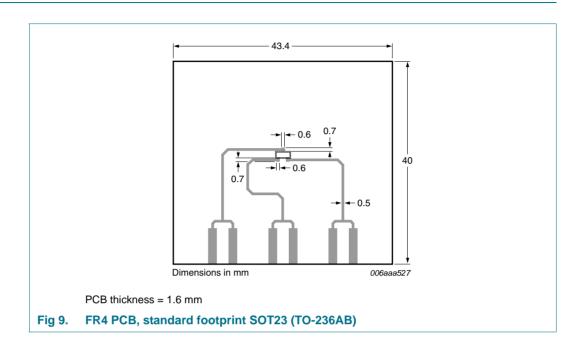
Type number	Package	Description	Packing quantity		
			3000	10000	
BAS101	SOT23	SOT23 4 mm pitch, 8 mm tape and reel	-215 -235	-235	
BAS101S					

^[1] For further information and the availability of packing methods, see Section 15.

11. Soldering



12. Mounting



BAS101; BAS101S

High-voltage switching diodes

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13. Revision history

Table 10. Revision history

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS101_BAS101S_2	20091214	Product data sheet	-	BAS101_BAS101S_1
Modifications:		eet was changed to reflect w legal definitions and disconing": updated		
BAS101_BAS101S_1	20060908	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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